

STANDARD RECOVERY DIODES

Stud Version

Features

- Wide current range
- High voltage ratings up to 2500V
- High surge current capabilities
- Stud cathode and stud anode version

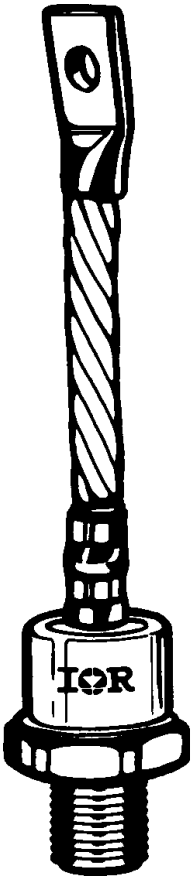
300A

Typical Applications

- Converters
- Power supplies
- Machine tool controls
- High power drives
- Medium traction applications

Major Ratings and Characteristics

Parameters	301U(R)		Units
	80 to 200	250	
$I_{F(AV)}$	330	300	A
	@ T_C	120	°C
$I_{F(RMS)}$	520	470	A
I_{FSM}	@ 50Hz	8250	A
	@ 60Hz	8640	A
I^2t	@ 50Hz	340	KA ² s
	@ 60Hz	311	KA ² s
V_{RRM} range	800 to 2000	2500	V
T_J	- 40 to 180	- 40 to 180	°C



case style
DO-205AB (DO-9)

301U(R) Series

ELECTRICAL SPECIFICATIONS

Voltage Ratings

Type number	Voltage Code	V_{RRM} , maximum repetitive peak reverse voltage V	V_{RSM} , maximum non-repetitive peak rev. voltage V	I_{RRM} max. @ $T_J = T_J$ max. mA
301U(R)	80	800	900	15
	120	1200	1300	
	160	1600	1700	
	200	2000	2100	
	250	2500	2600	

Forward Conduction

Parameter		301U(R)		Units	Conditions			
		80 to 200	250					
I _{F(AV)}	Max. average forward current @ Case temperature	330	300	A	180° conduction, half sine wave			
		120	120	°C				
I _{F(RMS)}	Max. RMS forward current	520	470	A	DC @ T _C = 115°C (08 to 20), T _C = 102°C (25)			
I _{FSM}	Max. peak, one-cycle forward, non-repetitive surge current	8250	6050	A	t = 10ms	No voltage	Sinusoidal half wave, Initial T _J = T _J max.	
		8640	6335		t = 8.3ms	reapplied		
		6940	5090		t = 10ms	100% V _{RRM}		
		7270	5330		t = 8.3ms	reapplied		
I ² t	Maximum I ² t for fusing	340	183	KA ² s	t = 10ms	No voltage		
		311	167		t = 8.3ms	reapplied		
		241	129		t = 10ms	100% V _{RRM}		
		220	118		t = 8.3ms	reapplied		
I ² √t	Maximum I ² /t for fusing	3400	1830	KA ² √s	t = 0.1 to 10ms, no voltage reapplied			
V _{F(TO)1}	Low level value of threshold voltage	0.77	0.90	V	(16.7% × π × I _{F(AV)} < I < π × I _{F(AV)}), T _J = T _J max.			
V _{F(TO)2}	High level value of threshold voltage	0.84	0.97		(I > π × I _{F(AV)}), T _J = T _J max.			
r _{f1}	Low level value of forward slope resistance	0.49	0.59	mΩ	(16.7% × π × I _{F(AV)} < I < π × I _{F(AV)}), T _J = T _J max.			
r _{f2}	High level value of forward slope resistance	0.49	0.55		(I > π × I _{F(AV)}), T _J = T _J max.			
V _{FM}	Max. forward voltage drop	1.22	1.46	V	I _{pk} = 942A, T _J = T _J max, t _p = 10ms sinusoidal wave			

Thermal and Mechanical Specifications

Parameter	301U(R)	Units	Conditions
T_J Max. junction operating temperature range	-40 to 180	°C	
T_{stg} Max. storage temperature range	-40 to 200		
R_{thJC} Max. thermal resistance, junction to case	0.14	K/W	DC operation
R_{thCS} Max. thermal resistance, case to heatsink	0.08		Mounting surface, smooth, flat and greased
T Max. allowed mounting torque +0 -20%	37	Nm	Not lubricated threads
	28		Lubricated threads
wt Weight	301U	g	
	303U		
	305U		
	307U		
	309U		
Case style	DO-205AB (DO-9)		See Outline Table

 ΔR_{thJC} Conduction

(The following table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction		Rectangular conduction		Units	Conditions
	80 to 200	250	00 to 200	250		
180°	0.015	0.015	0.011	0.011	K/W	$T_J = T_J \text{ max.}$
120°	0.018	0.018	0.019	0.019		
90°	0.023	0.023	0.025	0.025		
60°	0.034	0.034	0.035	0.035		
30°	0.056	0.056	0.057	0.057		

Ordering Information Table

Device Code

30	1	U	A	250	P5
①	②	③	④	⑤	⑥

- 1** - 30 = Essential Part Number
- 2** - 1 = Standard Device
 3 = Top Threaded version
 5 = Type for rotating application with Top Threaded version 3/8 16UNC-2A
 7 = Type for rotating application with flexible lead
 9 = Type for rotating application with Top Threaded version 3/8 24UNF
- 3** - U = Stud Normal Polarity (Cathode to Stud)
 UR = Stud Reverse Polarity (Anode to Stud)
- 4** - A = Max. Leakage selection $I_{RRM} = 2\text{mA}$ $T_J = 25^\circ\text{C}$
 None = Std. Leakage selection $I_{RRM} = 10\text{mA}$ $T_J = 25^\circ\text{C}$
- 5** - Voltage code: Code x 10 = V_{RRM} (See Voltage Ratings table)
- 6** - P. = Forward selection
 None = Standard Forward selection

RANGE	I_{FM} $T_J = 25^\circ\text{C}$ (A)	V_{FM} min. (V)	V_{FM} max. (V)
P2 *	1000	1.16	1.25
P3 *		1.26	1.30
P4		1.31	1.40
P5		1.41	1.45

* 2500V not available

301U(R) Series

Outline Table

CERAMIC HOUSING 19 (0.75) MAX. 24 (0.94) MAX. DIA. 8.7 (0.34) MAX. 140 (5.51) 146 (5.75) 28 (1.10) MAX. 21 (0.83) MAX. 3/4"-16UNF-2A 32 (1.26) 3.9 (0.15) 301U Case Style DO-205AB (DO-9)	CERAMIC HOUSING 19 (0.75) MAX. 11 (0.43) NOM. 12 (0.47) MIN. DIA. 8.5 (0.33) 140 (5.51) 148 (5.83) 54 (2.13) MAX. 21 (0.83) MAX. 3/4"-16UNF-2A 32 (1.26) 3.9 (0.15) 307U IR Case Style B60
All dimensions in millimeters (inches)	
CERAMIC HOUSING 3/8"-16UNC-2A 98 (3.86) MAX. 59 (2.32) MAX. 6.4 (0.25) MAX. 7 (0.28) MAX. 21 (0.83) MAX. 3/4"-16UNF-2A 32 (1.26) 16 (0.63) 305U IR Case Style B61	CERAMIC HOUSING 3/8"-24UNF-2A 97 (3.82) MAX. 60 (2.36) MAX. 7.6 (0.3) MAX. 7 (0.28) MAX. 21 (0.83) MAX. 3/4"-16UNF-2A 32 (1.26) 17.5 (0.69) 309U IR Case Style B41

Outline Table

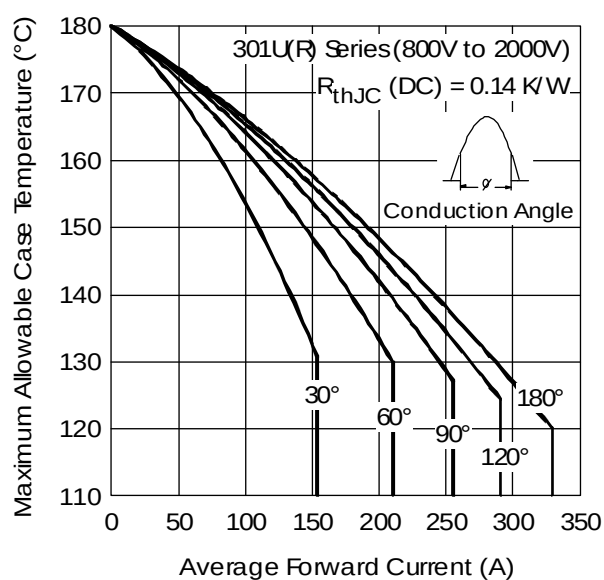
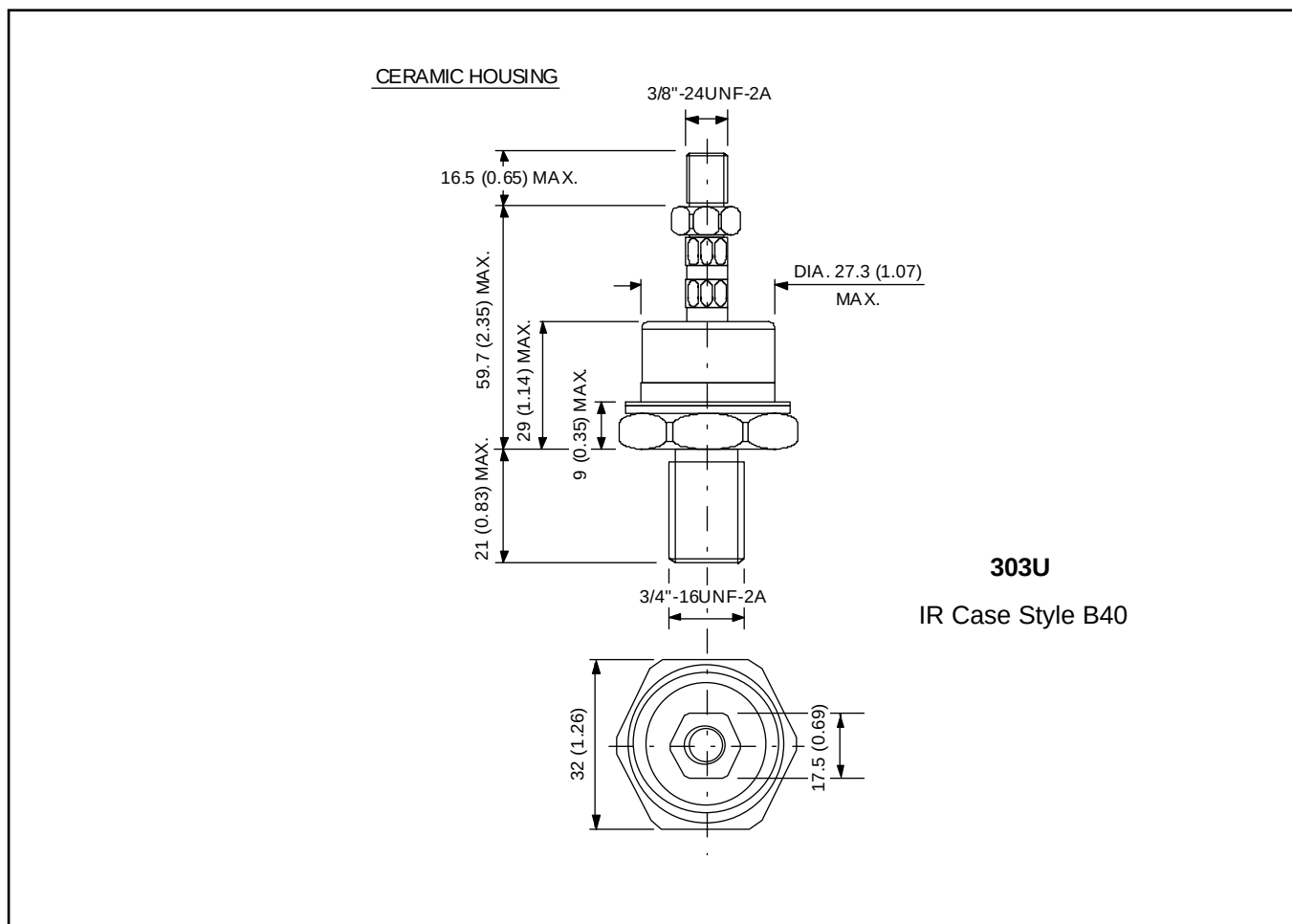


Fig. 1 - Current Ratings Characteristics

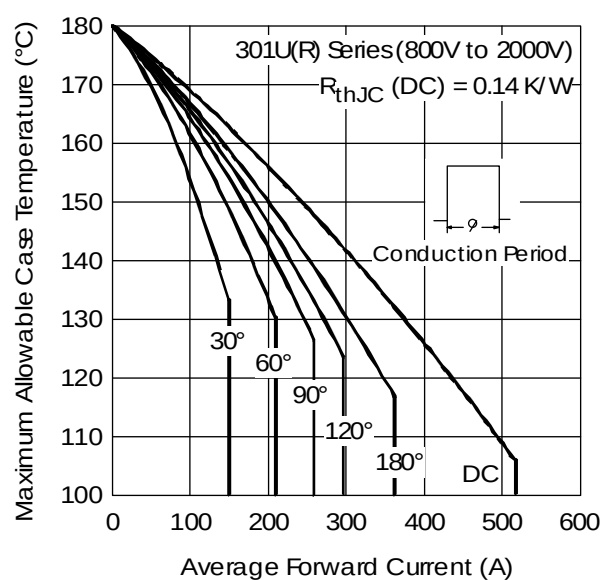


Fig.2 - Current Ratings Characteristics

301U(R) Series

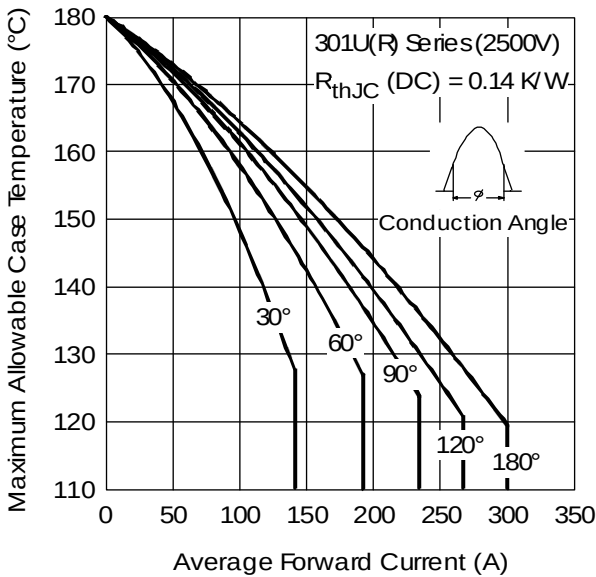


Fig. 3 - Current Ratings Characteristics

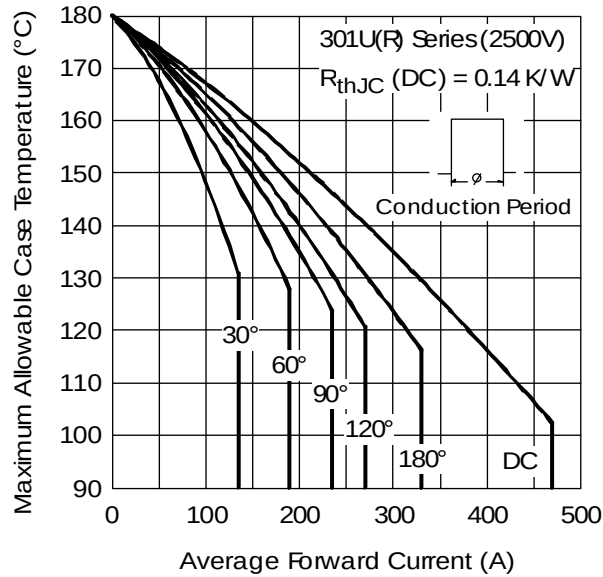


Fig. 4 - Current Ratings Characteristics

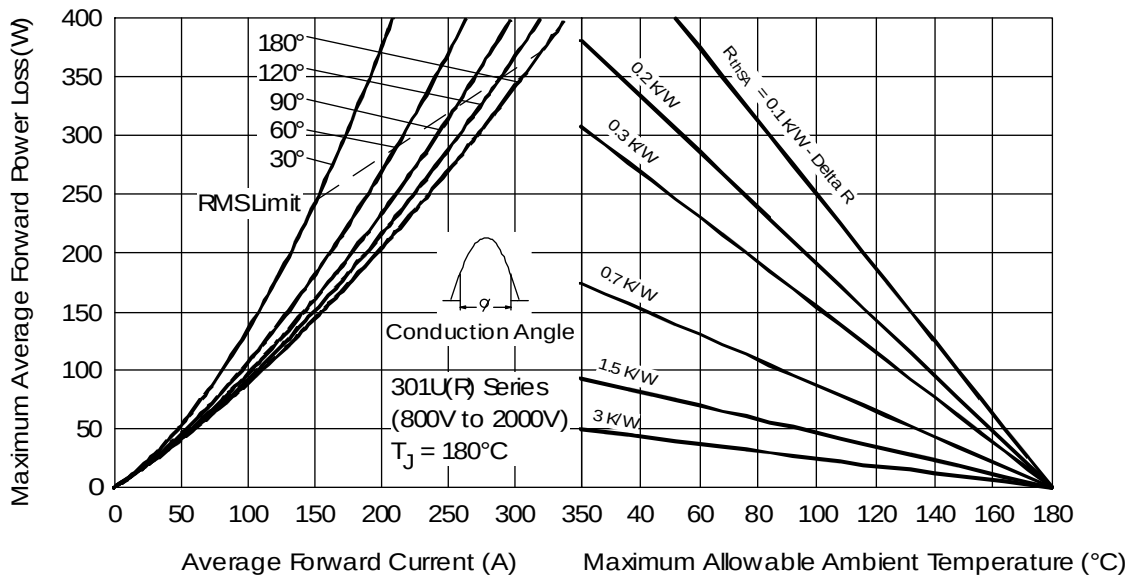


Fig. 5 - Forward Power Loss Characteristics

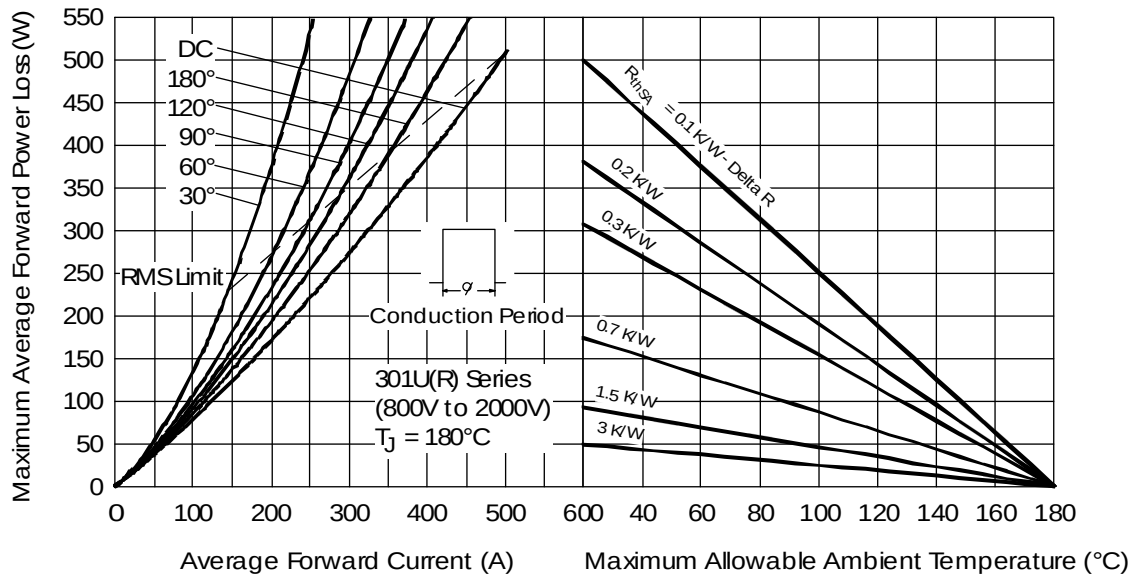


Fig. 6 - Forward Power Loss Characteristics

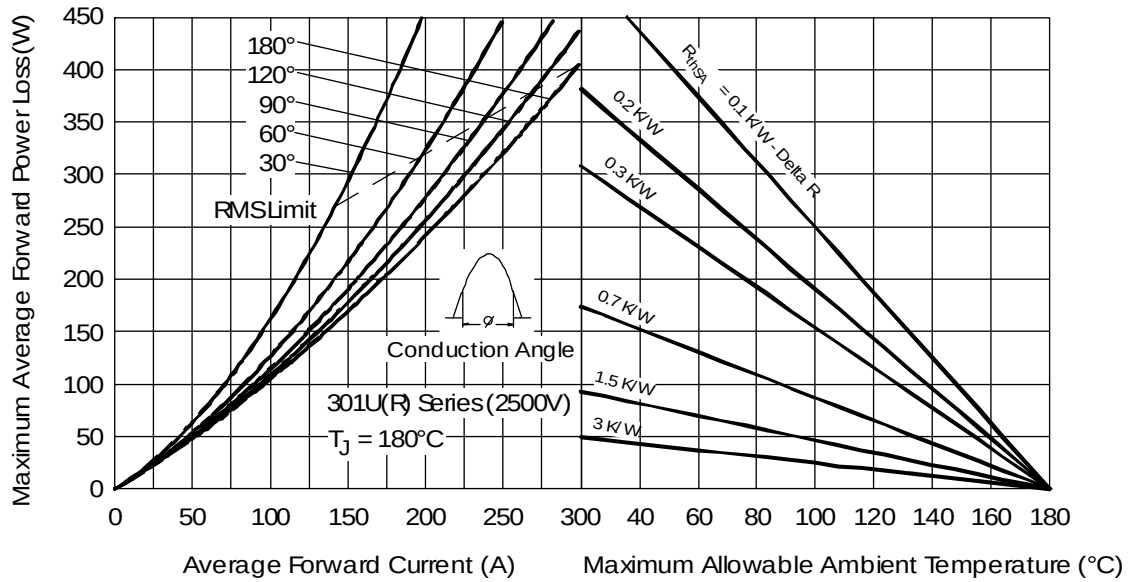


Fig. 7 - Forward Power Loss Characteristics

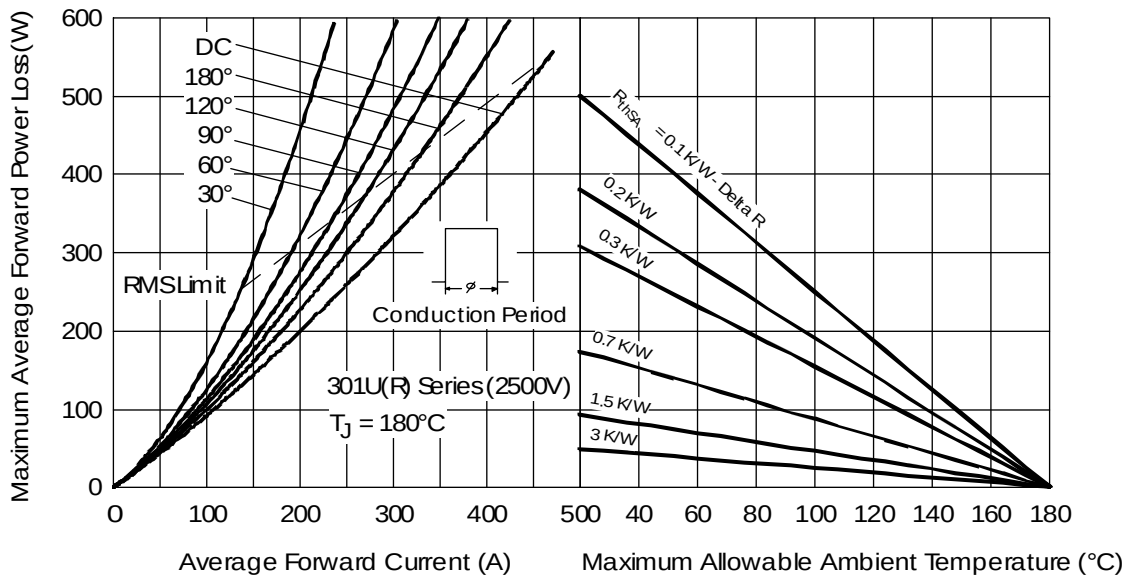


Fig. 8 - Forward Power Loss Characteristics

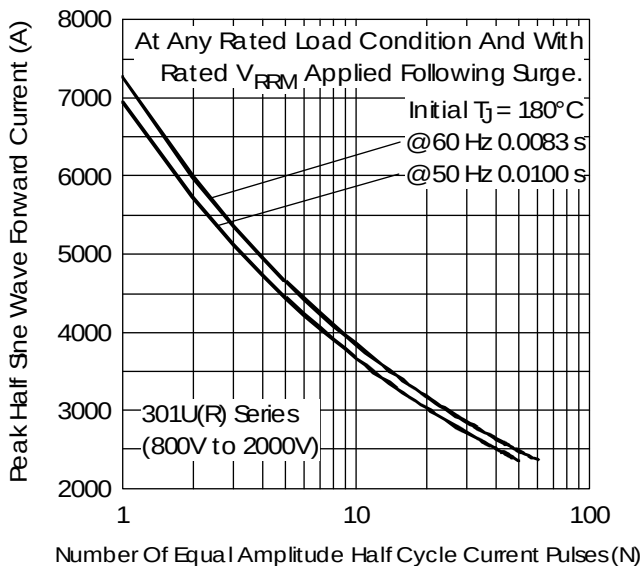


Fig. 9 - Maximum Non-Repetitive Surge Current

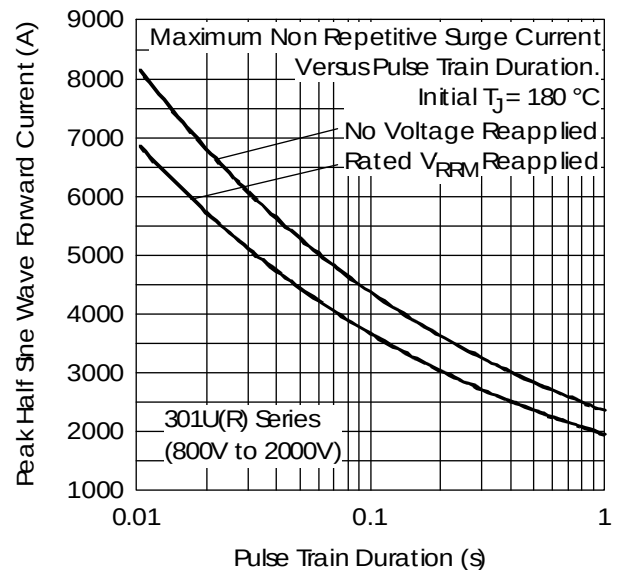


Fig. 10 - Maximum Non-Repetitive Surge Current

301U(R) Series

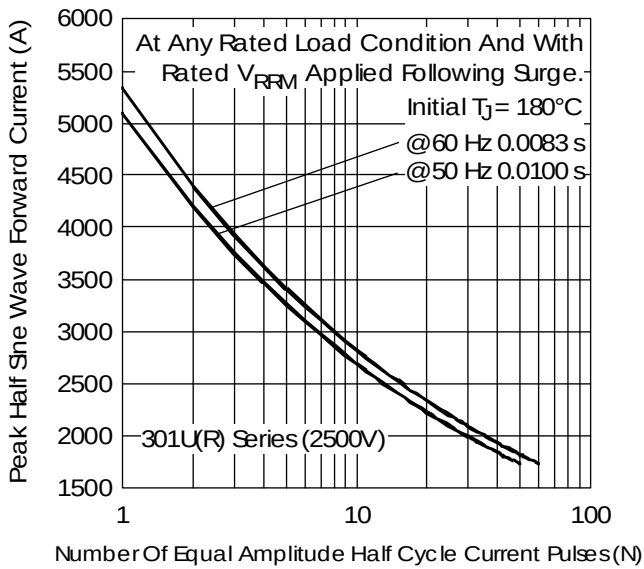


Fig. 11 - Maximum Non-Repetitive Surge Current

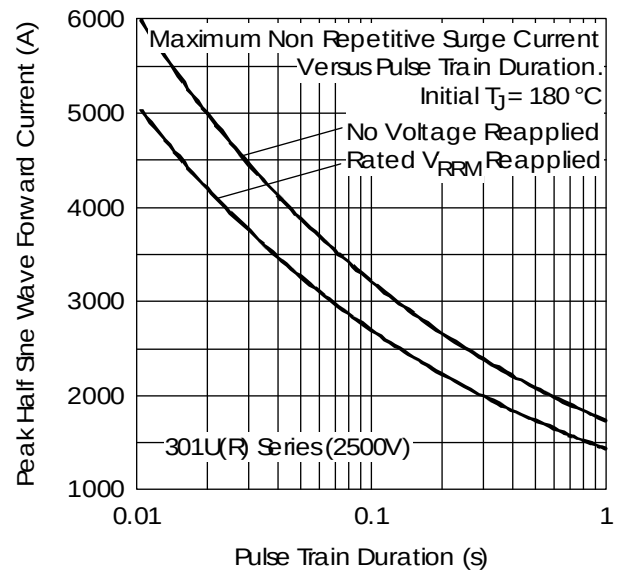


Fig. 12 - Maximum Non-Repetitive Surge Current

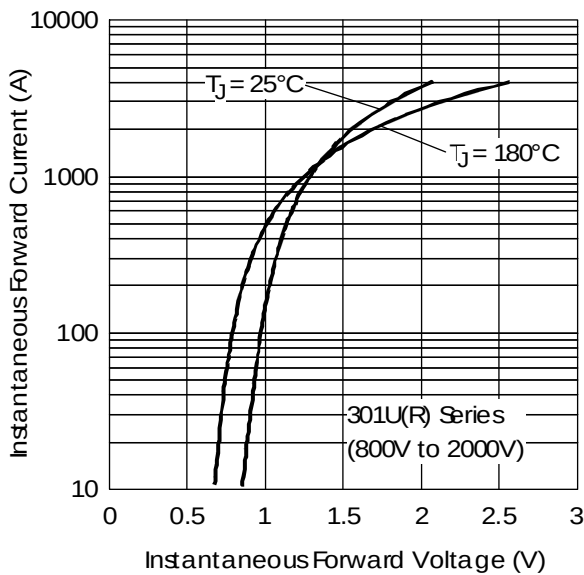


Fig. 13 - Forward Voltage Drop Characteristics

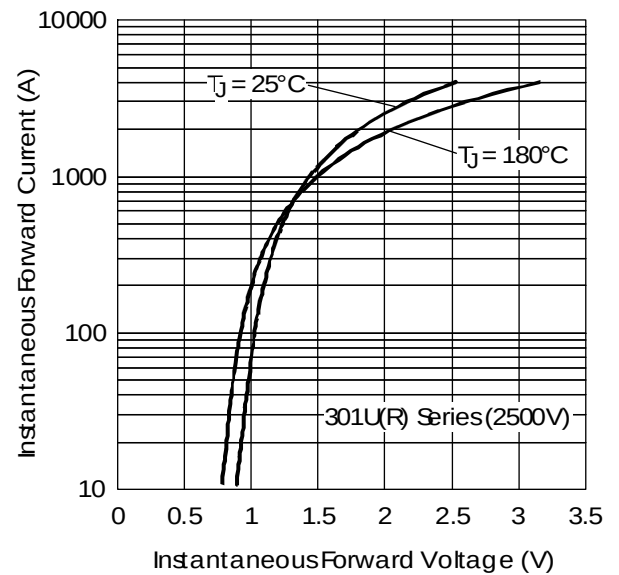


Fig. 14 - Forward Voltage Drop Characteristics

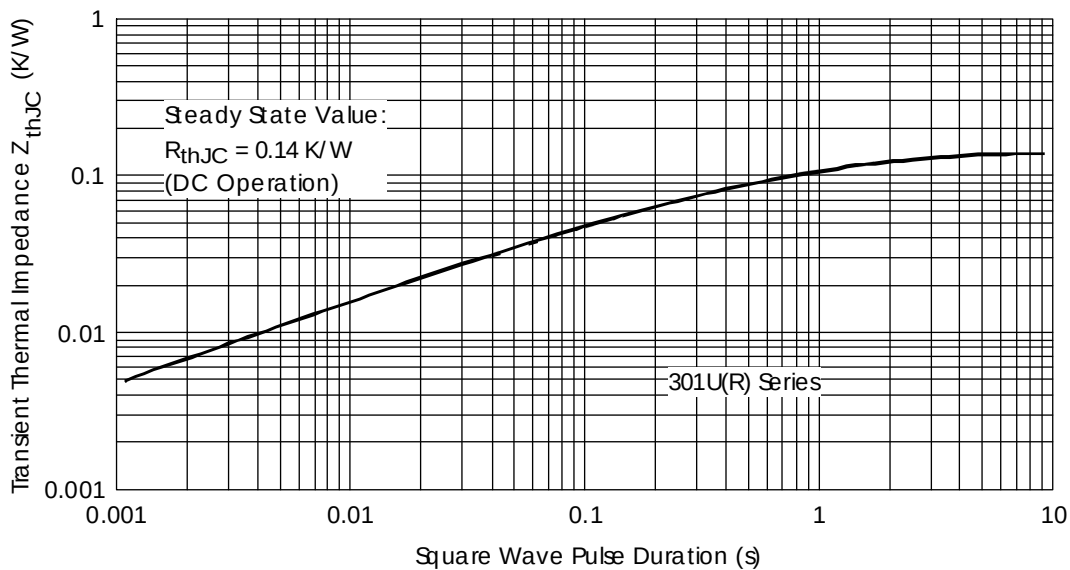


Fig. 15 - Thermal Impedance Z_{thJC} Characteristic

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

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В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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